

80V N-Channel Enhancement Mode MOSFET

Voltage	80 V	R _{DSON}	3.4 mΩ
Current	161 A	Q _G (TYP)	103.5 nC

Feature:

- R_{DSON} Max, V_{GS}@10V, I_D@50A<3.4mΩ
- R_{DSON} Max, V_{GS}@7V, I_D@25A<5mΩ
- 100% Avalanche Tested
- 100% R_g Tested
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

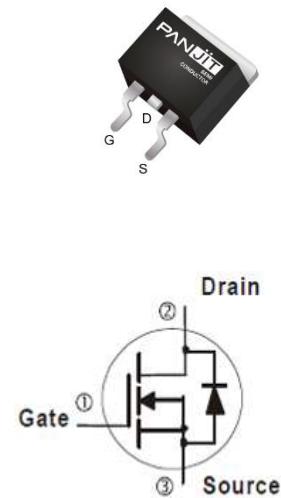
Mechanical Data

- Case: TO-263 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 1.38 grams

Application

- BMS, BLDC, SMPS SR.

TO-263



Absolute Maximum Ratings (T_A = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V _{DS}	80	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current	I _D	161	A
		102	
Pulsed Drain Current	I _{DM}	480	A
Single Pulse Avalanche Current (Note 5)	I _{AS}	38	A
Single Pulse Avalanche Energy (Note 5)	E _{AS}	722	mJ
Power Dissipation	P _D	156	W
		62.5	
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55~150	°C

Thermal Characteristics

PARAMETER	SYMBOL	MAXIMUM	UNITS
Thermal Resistance	R _{θJC}	0.8	°C/W
	R _{θJA}	62.5	°C/W

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS} ^(Note 7)	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	80	-	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	2.25	3.2	3.75	
Drain-Source On-State Resistance (Note 1)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=50\text{A}$	-	3	3.4	$\text{m}\Omega$
		$V_{\text{GS}}=7\text{V}, I_{\text{D}}=25\text{A}$	-	3.5	5	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=80\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	$V_{\text{DS}}=40\text{V}, I_{\text{D}}=50\text{A}, V_{\text{GS}}=7\text{V}$	-	76	-	nC
			-	103.5	-	
Gate-Source Charge	Q_{gs}	$V_{\text{DS}}=40\text{V}, I_{\text{D}}=50\text{A}, V_{\text{GS}}=10\text{V}$	-	34.1	-	
Gate-Drain Charge	Q_{gd}		-	20.9	-	
Input Capacitance	C_{iss}	$V_{\text{DS}}=40\text{V}, V_{\text{GS}}=0\text{V}, F=1\text{MHz}$	-	7430	-	pF
Output Capacitance	C_{oss}		-	1483	-	
Reverse Transfer Capacitance	C_{rss}		-	89	-	
Turn-On Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=40\text{V}, I_{\text{D}}=50\text{A}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=2\Omega$ (Note 2)	-	70.6	-	ns
Turn-On Rise Time	t_r		-	103	-	
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	122	-	
Turn-Off Fall Time	t_f		-	48.5	-	
Gate Resistance	R_g	$f=1.0\text{MHz}$	-	3.2	-	Ω
Drain-Source Diode						
Diode Forward Voltage	V_{SD}	$I_s=50\text{A}, V_{\text{GS}}=0\text{V}$	-	0.88	1.2	V
Reverse Recovery Charge	Q_{rr}	$I_s=50\text{A}$ $dI/dt=100\text{A}/\mu\text{s}$	-	114	-	nC
Reverse Recovery Time	T_{rr}		-	69	-	ns

NOTES :

1. Pulse width < 580us,
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is silicon limited.
4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. The test condition is $L=1\text{mH}, I_{\text{AS}}=38\text{A}, V_{\text{DD}}=40\text{V}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=25\text{ohm}$, Starting $T_J=25^\circ\text{C}$
6. Guaranteed by design, not subject to production testing.
7. BVDSS is over 85V during mass production.

TYPICAL CHARACTERISTIC CURVES

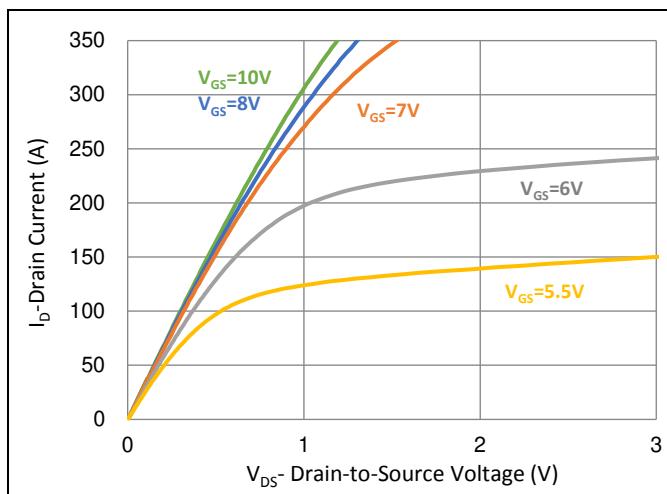


Fig.1 Output Characteristics

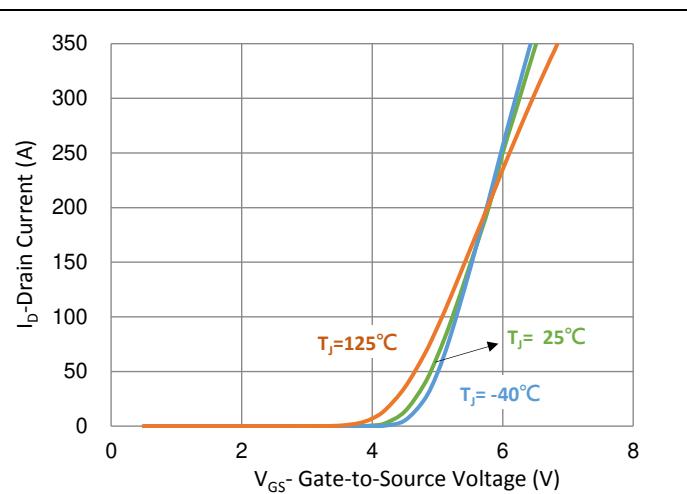


Fig.2 Transfer Characteristics

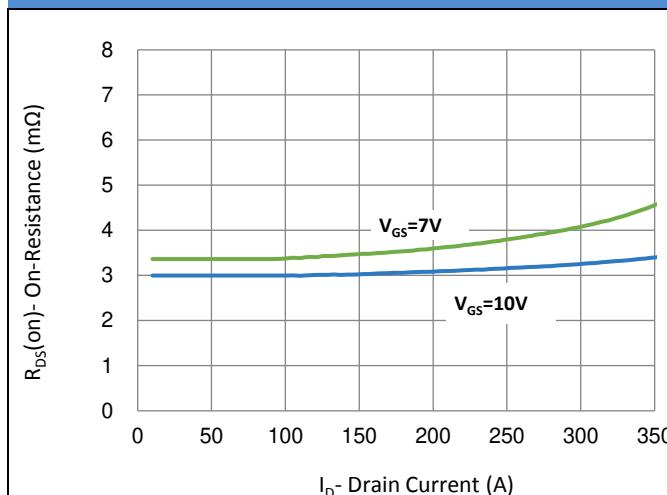


Fig.3 On-Resistance vs. Drain Current

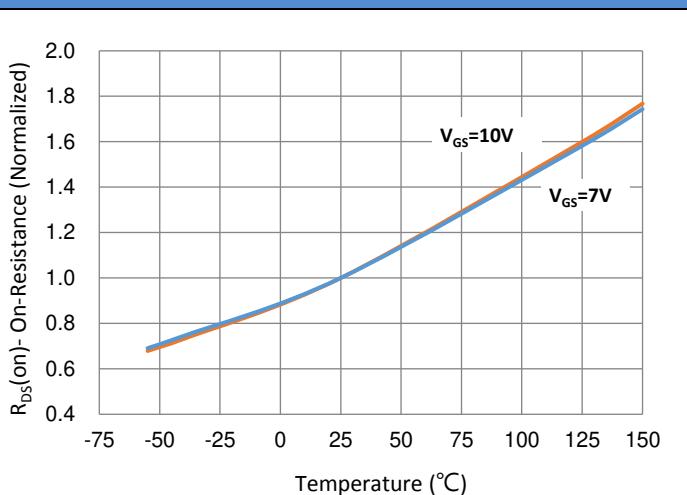


Fig.4 On-Resistance vs. Junction Temperature

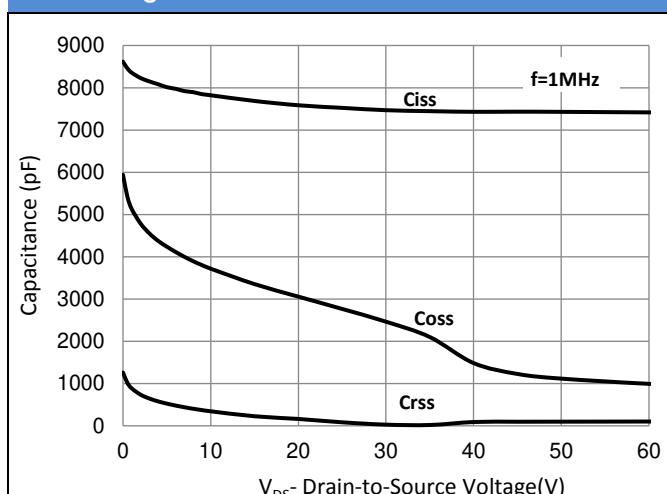


Fig.5 Capacitance vs. Drain-Source Voltage

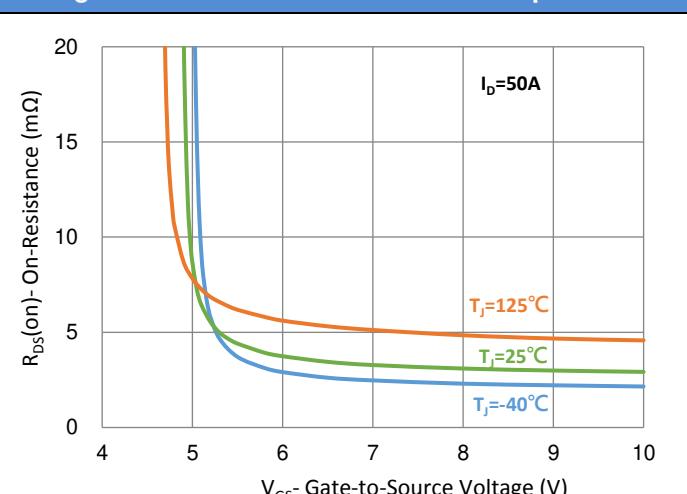
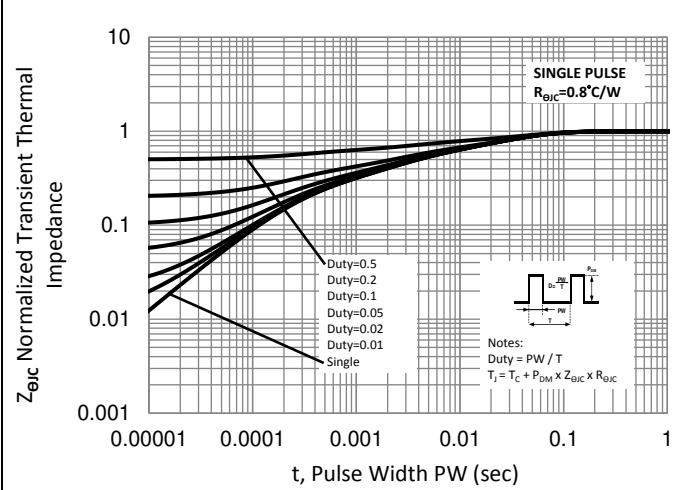
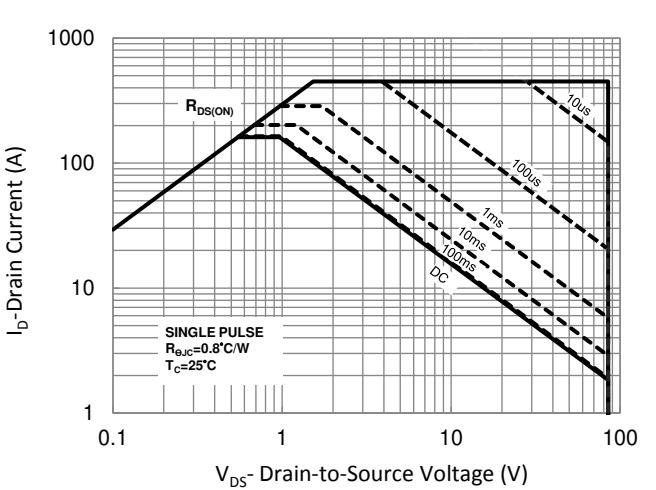
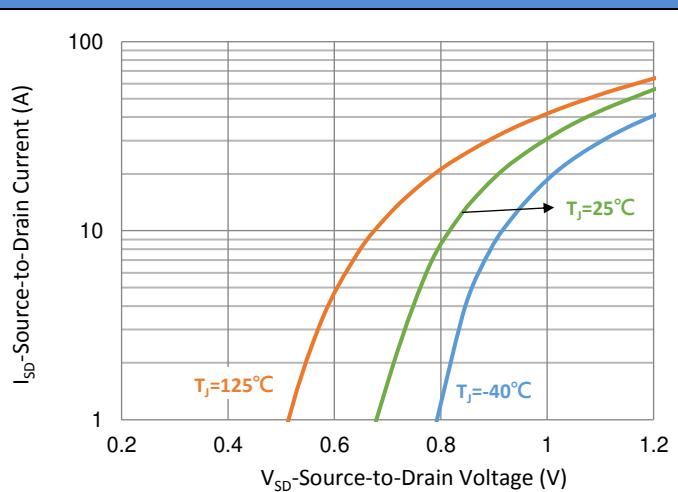
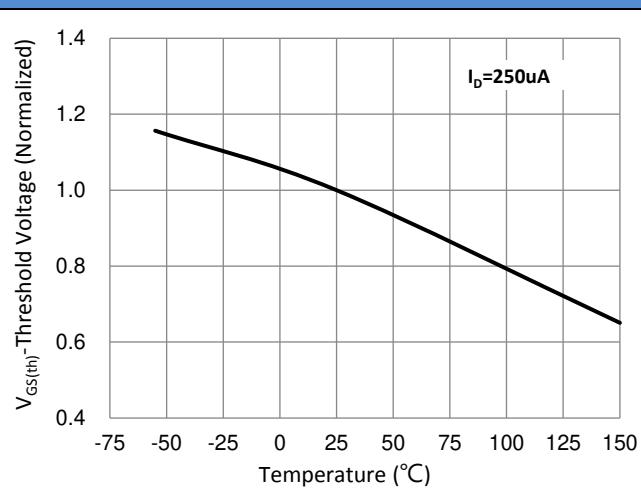
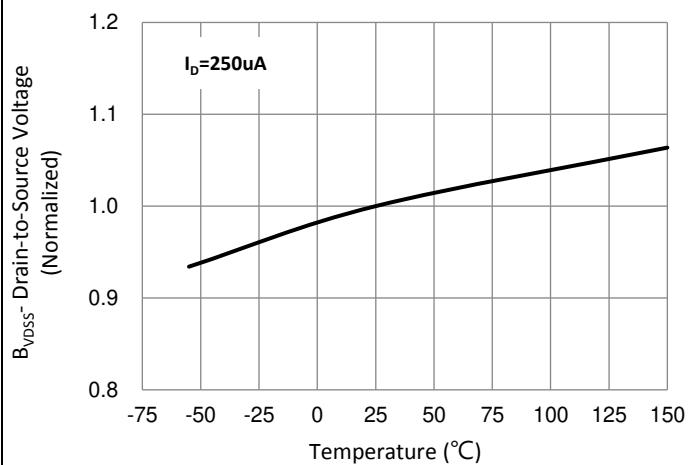
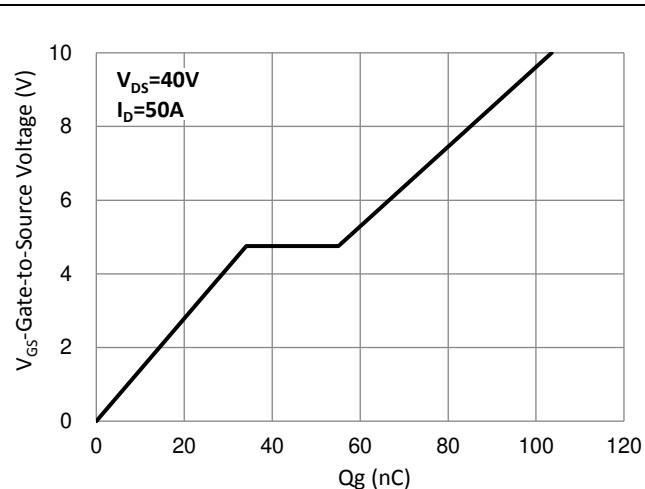


Fig.6 On-Resistance vs. Gate-Source Voltage

TYPICAL CHARACTERISTIC CURVES



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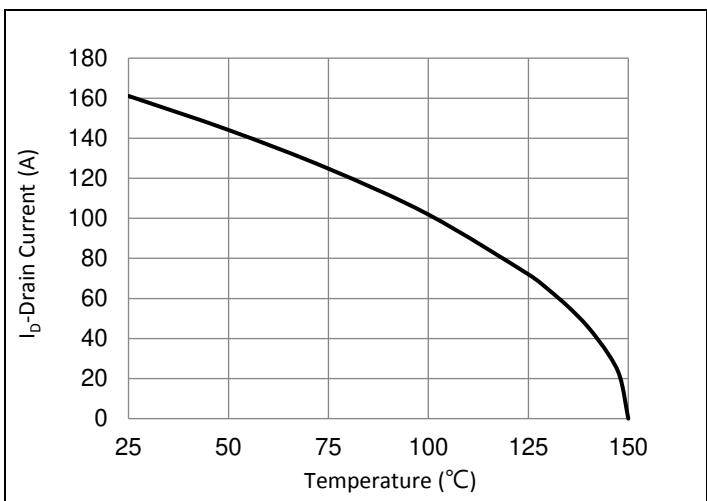
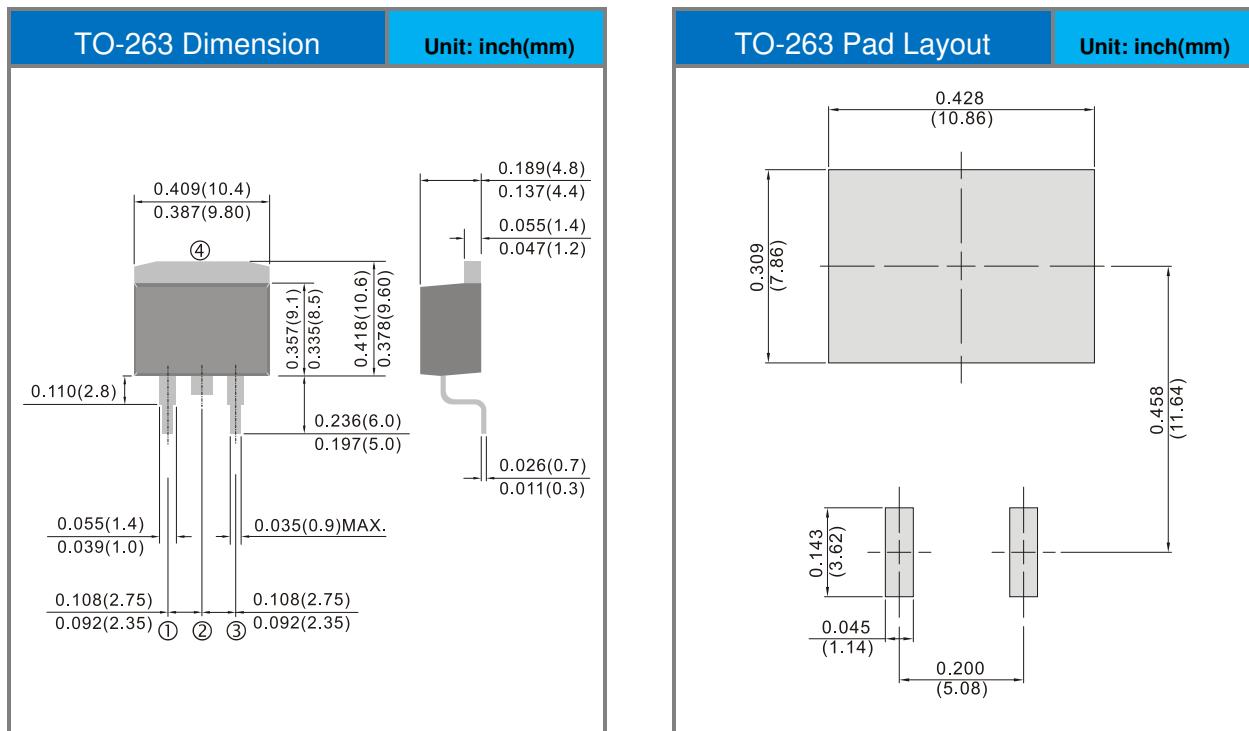


Fig.13 Drain Current vs. Case Temperature

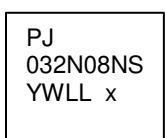
Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PSMB032N08NS1	TO-263	50pcs / Tube 800pcs / Reel	032N08NS

Packaging Information & Mounting Pad Layout



Marking Diagram



PJ = Year Code
W = Week Code (A~Z)
LL = Lot Code (00~99)
x = Production Line Code

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